

## R-C Thermal Model Parameters

### DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

### R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	2.7571	785.3683 m	N/A
RT2	8.9502	137.9901 m	N/A
RT3	10.5524	390.5275 m	N/A
RT4	27.7084	386.1141 m	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	22.3993 m	12.3931 m	N/A
CT2	431.7358 m	9.1847 m	N/A
CT3	2.6683	280.8023 m	N/A
CT4	4.1807	1.7131 m	N/A

**Note**

N/A indicates not applicable

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.*

**R-C THERMAL MODEL FOR FILTER CONFIGURATION**



<b>R-C VALUES FOR FILTER CONFIGURATION</b>			
<b>THERMAL RESISTANCE (°C/W)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
RF1	2.8457	541.4117 m	N/A
RF2	10.2462	698.2421 m	N/A
RF3	15.5302	352.2096 m	N/A
RF4	21.2510	112.4902 m	N/A
<b>THERMAL CAPACITANCE (Joules/°C)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
CF1	18.7147 m	1.3051 m	N/A
CF2	270.8021 m	8.1007 m	N/A
CF3	886.9383 m	117.6379 m	N/A
CF4	3.5282	1.5863	N/A

**Note**

N/A indicates not applicable

